

General Description

The MAX320/MAX321/MAX322 are precision, dual. SPST analog switches designed to operate from ±3V to ±8V dual supplies. The MAX320 has two normally open (NO) switches and the MAX321 has two normally closed (NC) switches. The MAX322 has one NO and one NC switch. Low power consumption (1.25mW) makes these parts ideal for battery-powered equipment. They offer low leakage currents (100pA max) and fast switching speeds (ton = 150ns max, toff = 100ns

The MAX320 series, powered from ±5V supplies, offers 35Ω max on-resistance (RON), 2Ω max matching between channels, and 4Ω max Ron flatness.

These switches also offer 5pC max charge injection and a minimum of 2000V ESD protect on per Method 3015.7.

For equivalent devices specified for single-supply operation, see the MAX323/MAX324/MAX325 data sheet. For auad versions of these switches, see the MAX391/MAX392/MAX393 data sheet

Applications

Battery-Operated Systems

Heads-Up Displays

Audio and Video Switching

Test Equipment ±5V DACs and ADCs Sample-and-Hold Circuits Guidance and Control Systems

Military Radios

Communications Systems

PBX, PABX

Features

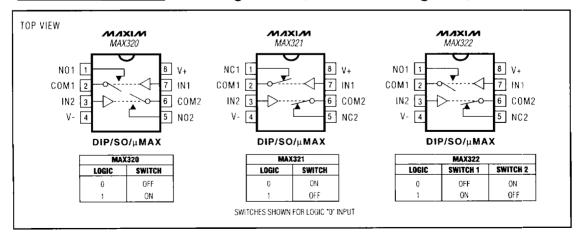
- Low On-Resistance, 35Ω max (16Ω typical)
- Ron Matching Between Channels <2Ω
- ♦ Ron Flatness <4Ω</p>
- ♦ Guaranteed Charge Injection <5pC</p>
- ◆ Bipolar Supply Operation (±3V to ±8V)
- ♦ Low Power Consumption, <1.25mW</p>
- Low Leakage Current Over Temperature. <2.5nA at +85°C
- Fast Switching, ton <150ns, toff <100ns
- Guaranteed Break-Before-Make (MAX322 only)

Ordering Information

MAX320CPA 0°C to +70°C 8 Plastic DIP MAX320CSA 0°C to +70°C 8 SO MAX320CUA 0°C to +70°C 8 µMAX MAX320C/D 0°C to +70°C Dice*
MAX320CUA 0°C to +70°C 8 μMAX
MAY2000(D) 000 to 7000 Dis-st
MAX320C/D 0°C to +70°C Dice*
MAX320EPA -40°C to +85°C 8 Plastic DIP
MAX320ESA -40°C to +85°C 8 SO
MAX320EJA -40°C to +85°C 8 CERDIP**
MAX320MJA -55°C to +125°C 8 CERDIP**

Ordering Information continued at end of data sheet.

Pin Configurations/Functional Diagrams/Truth Tables



MIXLM

Maxim Integrated Products 1

Contact factory for dice specifications. ** Contact factory for availability.

ABSOLUTE MAXIMUM RATINGS

Voltage Referenced to V-	
V+(V 0.3V) to +17V	i
IN_, COM_, NC_, NO_ (Note 1)(V~ - 0 3V) to (V+ + 0.3V)	O
Continuous Current (any terminal)	Ì
Peak Current, COM_, NO_, NC_	
(pulsed at 1ms, 10% duty cycle max) 100mA	1
ESD per Method 3015.7>2000V	St
Continuous Power Dissipation	Le
Plastic DIP (derate 9.09mW/°C above +70°C)727mW	
Narrow SQ (derate 5.88mW/°C above +70°C)	

μMAX (derate 4.10mW/°C above +70°C)	330mW
CERDIP (derate 8.00mW/°C above +70°C)	640mW
Operating Temperature Ranges	
MAX32_C	0°C to +70°C
MAX32_E	40°C to +85°C
MAX32_MJA	55°C to +125°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (soldering, 10sec)	+300°C

Note 1: Signals on NC_, NO_, COM_, or IN_ exceeding V+ or V- are clamped by internal diodes. Limit forward diode current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

 $(V + = +5V \pm 10\%, V - = -5V \pm 10\%, V_{INH} \approx 3.5V, V_{INL} = 2.5V, T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted.)

PARAMETER	SYMBOL	COND	ITIONS		MIN	TYP (Note 2)	MAX	UNITS
ANALOG SWITCH								
Analog Signal Range	VCOM, VNO. VNC	(Note 3)			V-		V+	٧
On-Resistance		V+ = 4.5V, V- = -4.5V,	T _A =	C, E		16	35	
	RON		+25°C	М		16	30	Ω
		ICOM ≈ 1.0mA, VNO or VNC = ±3.5V	TA ≈ T _{MIN} to T _{MAX}				45	
On-Resistance Match Between Channels (Note 4)	ΔRON	V+ = 5V, V- = -5V, ICOM ≈ 1.0mA,				0.3	2	Ω
	211011	V _{NO} or V _{NC} = ±3V		to T _{MAX}			4	72
On-Resistance Flatness (Note 5)	Del ATIONS	V+ = 5V, V- = -5V,		С		1	4	Ω
	RFLAT(ON)	ICOM = 1.0mA, V_{NO} or $V_{NC} = \pm 3V$		to T _{MAX}			6	1 1
NO or NC Off Leakage Current	INO(CFF)	V+ = 5.5V, V- = -5.5V, VCOM = ±4.5V, VNO OR VNC = ∓4.5V	TA = +25°		-0.1	0.01	0,1	
(Note 6)	INC(OFF)		TA = TMIN	C, E	-5		5	nA
	110(011)		to TMAX	М	-40		40	1 !
COM Off Leakage Current (Note 6)		V+ = 5.5V, V- = -5.5V, VCOM = ±4.5V, VNO OF VNC = ∓4.5V	TA = +25°	С	-0.1	0.01	0.1	
	COM(OFF)		TA = TMIN	C, E	-5		5	nA nA
			to TMAX	М	-40		40]
COM On Leakage Current (Note 6)	ICOM(ON)	$VCOM = \pm 4.5V$	TA = +25°	С	-0.2	0.05	0.2	nA
			TA = TMIN	C, E	-10		10] ''^
		V_{NO} or $V_{NC} \approx \pm 4.5 V$	to TMAX	M	-50		50	

ELECTRICAL CHARACTERISTICS

 $(V + = +5V \pm 10\%, V - = -5V \pm 10\%, V_{INH} = 3.5V, V_{INL} = 2.5V, T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS
LOGIC INPUT	1						
Input Current with Input Voltage High	linh			-0.5	0.005	0.5	μА
Input Current with Input Voltage Low	INL			-0.5	0.005	0.5	μA
Input Voltage High	VINH	$V+ = 5V \pm 10\%, V- \le 0V$ $3V < V+ < 8V, V- \le 0V$		3.5	V+ - 1.5		V
Input Voitage Low	VINL	$V + = 5V \pm 10\%, V - \le 0V$ $3V < V + < 8V, V - \le 0V$			V+ - 2.5	2.5	V
DYNAMIC							
Turn-On Time	ton	V _{COM} = ±3V, Figure 2	TA = +25°C TA = TMIN to TMAX		65	150 175	ns
Turn-Off Time	toff	VCOM = ±3V, Figure 2	TA = +25°C TA = TMIN to TMAX		35	100 150	ns
Break-Before-Make Time Delay (Note 3)	tD	MAX322 only, $R_L = 300\Omega$	2	5		ns	
Charge Injection (Note 3)	Q	$C_L = 1.0$ nF, $V_{GEN} = 0V$, $R_{GEN} = 0\Omega$, Figure 4	T _A = +25°C		2	5	рС
Off Isolation (Note 7)	OIRR	$R_L = 50\Omega$, $C_L = 5pF$, $f = 1MHz$, Figure 5	T _A = +25°C		72		dB
Crosstalk (Note 8)		$R_L = 50\Omega$, $C_L = 5pF$, $f = 1MHz$, Figure 6	T _A = +25°C		85		dB
NC or NO Capacitance	C(OFF)	f = 1MHz, Figure 7	T _A = +25°C		9		pF
COM Off Capacitance	CCOM(OFF)	f = 1MHz, Figure 7	T _A = +25°C		9		рF
COM On Capacitance	Ссом(ом)	f = 1MHz, Figure 8	T _A = +25°C		22		рF
SUPPLY							,
Power-Supply Range		,	_	±2.7		±8	V
Positive Supply Current	l+	$V+ = 5.5V$, $V- = -5.5V$, $V_{IN} = 0V$ or $V+$,	T _A = +25°C	-125	80	125	μA
		all channels on or off	TA = TMIN to TMAX	-200		200	
Negative Supply Current	I-	$V+ = 5.5V$, $V- = -5.5V$, $V_{IN} = 0V$ or $V+$,	T _A = +25°C	-125	80	125	μA
		all channels on or off	$T_A = T_{MIN}$ to T_{MAX}	-200		200	

Note 2: The algebraic convention where the most negative value is a minimum and the most positive value a maximum is used in this data sheet.

Note 3: Guaranteed by design.

Note 4: $\Delta R_{ON} = \Delta R_{ON} \max - \Delta R_{ON} \min$.

Note 5: Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal range.

Note 6: Leakage parameters are 100% tested at maximum rated hot temperature and guaranteed by correlation at +25°C.

Note 7: Off Isolation = 20 log10 [VCOM / (VNC or VNO)]. VCOM = output, VNC or VNO = input to off switch.

Note 8: Between any two switches

Typical Operating Characteristics

 $(V+=+5V, V-=-5V, T_A=+25^{\circ}C, unless otherwise noted.)$

ON-DEGICTANCE VE VOI TAGE AT COM PIN

ON-RESISTANCE VS. VOLTAGE AT COM PIN

ON-RESISTANCE MATCH vs. VOLTAGE
- AT COM PIN (OVER TEMPERATURE)

Pin Description

PIN	NAME	FUNCTION		
1	NO1 (MAX320/MAX322)	Normally Open Analog Switch Terminal		
'	NC1 (MAX321)	Normally Closed Analog Switch Terminal		
2, 6	COM1, COM2	Analog Switch Common Terminals		
3, 7	IN2, IN1	Logic Inputs		
4	V-	Negative Supply		
5	NO2 (MAX320)	Normally Open Analog Switch Terminal		
	NC2 (MAX321/MAX322)	Normally Closed Analog Switch Terminal		
8	V+	Positive Supply		

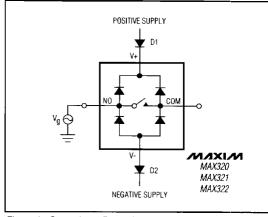


Figure 1. Overvoltage Protection Using Two External Blocking Diodes

Applications Information

Logic Levels

Calculate the logic thresholds typically as follows: $V_{IH} = (V + -1.5V)$ and $V_{II} = (V + -2.5V)$.

Power-supply consumption is minimized when IN1 and IN2 are driven with logic-high levels equal to V+ and logic-low levels well below the calculated V_{IL} of (V+ - 2.5V). IN1 and IN2 can be driven to V- without damage.

Analog Signal Levels

Analog signals that range over the entire supply voltage (V- to V+) can be switched, with very little change in on-resistance over the entire voltage range (see *Typical Operating Characteristics*). All switches are bidirectional, so NO_, NC_, and COM_ pins can be used as either inputs or outputs.

Power-Supply Sequencing and Overvoltage Protection

Do not exceed the absolute maximum ratings, because stresses beyond the listed ratings may cause permanent damage to the devices.

Proper power-supply sequencing is recommended for all CMOS devices. Always apply V+, followed by V-, before applying analog signals or logic inputs, especially if the analog or logic signals are not current-limited. If

this sequencing is not possible, and if the analog or logic inputs are not current-limited to <30mA, add two small signal diodes (D1, D2) as shown in Figure 1. Adding protection diodes reduces the analog signal range to a diode drop (about 0.7V) below V+ for D1, and a diode drop above V- for D2. Leakage is not affected by adding the diodes. On-resistance increases by a small amount at low supply voltages. Maximum supply voltage (V- to V+) must not exceed 17V.

Adding protection diode D1 causes the logic thresholds to be shifted relative to the positive power-supply rail. This can be significant when low positive supply voltages (+5V or less) are used. Driving IN1 and IN2 all the way to the supply rails (i.e., to a diode drop higher than the V+ pin or a diode drop lower than the V- pin) is always acceptable.

The protection diodes D1 and D2 also protect against some overvoltage situations. With the circuit of Figure 1, if the supply voltage is below the absolute maximum rating and if a fault voltage up to the absolute maximum rating is applied to an analog signal pin, no damage will result. For example, with ±5V supplies, analog signals up to ±8.5V will not damage the circuit of Figure 1. If only a single fault signal is present, the fault voltage can rise to +12V or to -12V without damage.

Test Circuits/Timing Diagrams

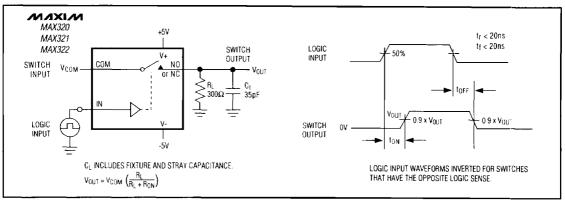


Figure 2. Switching Time

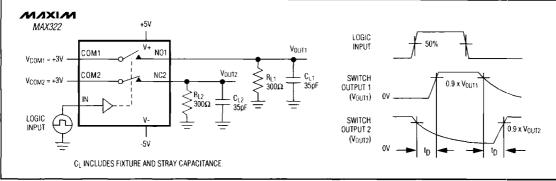


Figure 3. Break-Before-Make Interval (MAX322 only)

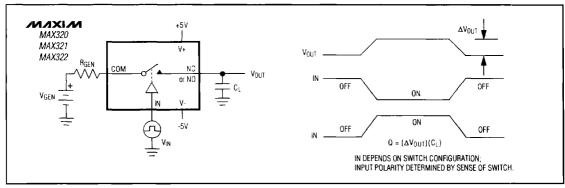


Figure 4. Charge Injection

_Test Circuits/Timing Diagrams (continued)

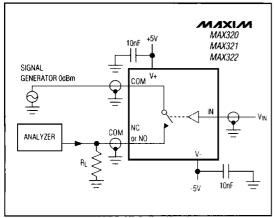


Figure 5. Off Isolation

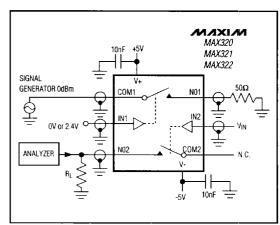


Figure 6. Crosstalk

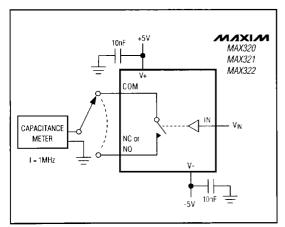


Figure 7. Channel-Off Capacitance

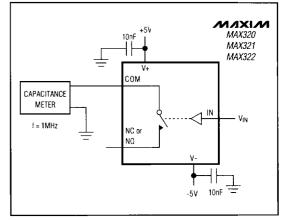


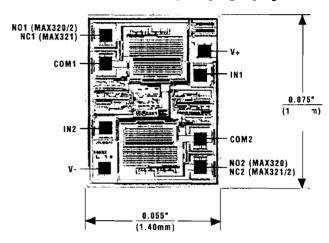
Figure 8. Channel-On Capacitance

_Ordering Information (continued)

PART	TEMP. RANGE	PIN-PACKAGE
MAX321CPA	0°C to +70°C	8 Plastic DIP
MAX321CSA	0°C to +70°C	8 SO
MAX321CUA	0°C to +70°C	8 µMAX
MAX321C/D	0°C to +70°C	Dice*
MAX321EPA	-40°C to +85°C	8 Plastic DIP
MAX321ESA	-40°C to +85°C	8 SO
MAX321EJA	-40°C to +85°C	8 CERDIP**
MAX321MJA	-55°C to +125°C	8 CERDIP**
MAX322CPA	0°C to +70°C	8 Plastic DIP
MAX322CSA	0°C to +70°C	8 SO
MAX322CUA	0°C to +70°C	8 µMAX
MAX322C/D	0°C to +70°C	Dice*
MAX322EPA	-40°C to +85°C	8 Plastic DIP
MAX322ESA	-40°C to +85°C	8 SO
MAX322EJA	-40°C to +85°C	8 CERDIP**
MAX322MJA	-55°C to +125°C	8 CERDIP**

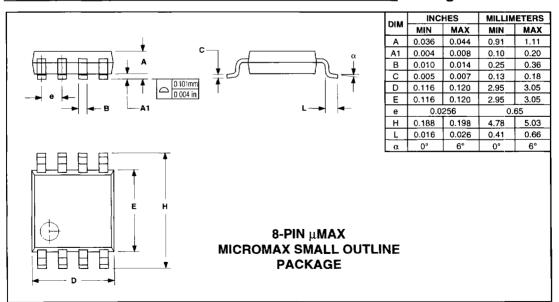
^{*} Contact factory for dice specifications.

_Chip Topography



TRANSISTOR COUNT: 91
SUBSTRATE CONNECTED TO V+

Package Information



Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

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^{**} Contact factory for availability.